**24 November 2023** 

Product data sheet

## 1. General description

100 mA PNP Resistor-Equipped Transistor (RET) in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

NPN complement: PDTC123YQB

#### 2. Features and benefits

- 100 mA output current capability
- **Built-in resistors**
- Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint

## 3. Applications

- Digital applications
- Cost saving alternative for BC847 series in digital applications
- Controlling IC inputs
- Switching loads

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	3.6	4.5	5.5	

[1] See "Section 11: Test information" for resistor calculation and test conditions.



50 V, 100 mA PNP resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2: 10 k $\Omega$ 

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	1	input (base)		
2	GND	ground (emitter)	3	
3	0	output (collector)	Transparent top view DFN1110D-3 (SOT8015)	GND

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package					
	Name	Description	Version			
PDTA123YQB	DFN1110D-3	plastic, leadless extremely thin small outline package with side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; 1.1 mm x 1 mm x 0.48 mm body	SOT8015			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PDTA123YQB	QD

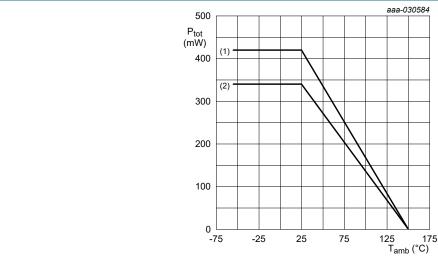
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
VI	input voltage			-12	5	V
Io	output current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	340	mW
			[2]	-	420	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



- (1) FR4 PCB, single-sided 70 µm copper, standard footprint
- (2) FR4 PCB, single-sided 35 µm copper, standard footprint

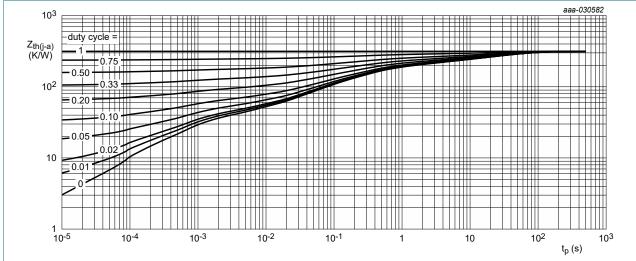
Fig. 1. Power derating curve SOT8015 (DFN1110D-3)

### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

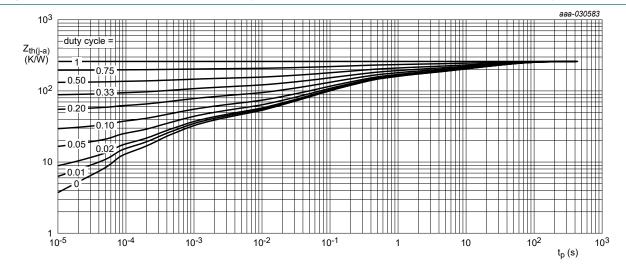
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uiy-a)	thermal resistance from	in free air	[1]	-	-	368	K/W
	junction to ambient		[2]	-	-	298	K/W

- [1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



FR4 PCB, single-sided 35 µm copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, single-sided 70 µm copper, tin-plated and standard footprint

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	' <sub>CB</sub> = -50 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-700	μA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -5 V; $I_{C}$ = -5 mA; $T_{amb}$ = 25 °C		35	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	-150	mV
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}$ = -5 V; $I_{C}$ = -100 $\mu$ A; $T_{amb}$ = 25 °C		-	-0.75	-0.3	V
$V_{I(on)}$	on-state input voltage	$V_{CE}$ = -300 mV; $I_{C}$ = -20 mA; $T_{amb}$ = 25 °C		-2.5	-1.15	-	V
R1	bias resistor 1 (input)		[1]	1.54	2.2	2.86	kΩ
R2/R1	bias resistor ratio		[1]	3.6	4.5	5.5	
C <sub>c</sub>	collector capacitance	$V_{CB}$ = -10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	180	-	MHz

- [1] See "Section 11: Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor.

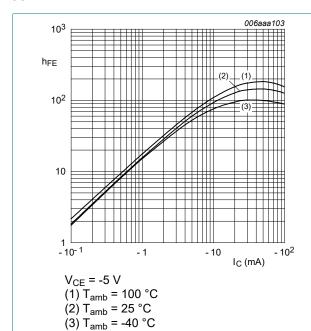
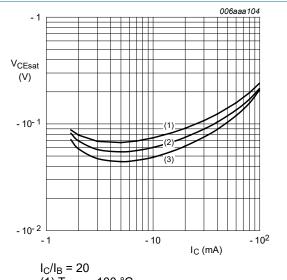


Fig. 4. DC current gain as a function of collector current; typical values



(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = -40 \, ^{\circ}C$ 

Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values

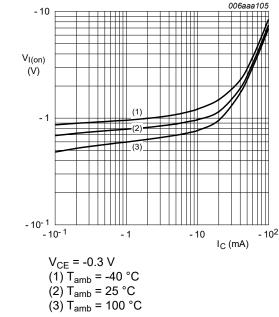
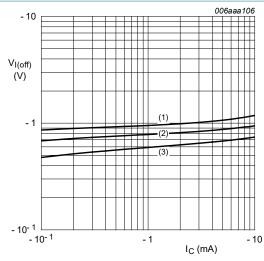
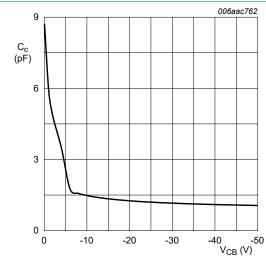


Fig. 6. On-state input voltage as a function of collector | Fig. 7. current; typical values



V<sub>CE</sub> = -5 V (1) T<sub>amb</sub> = -40 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

Off-state input voltage as a function of collector current; typical values



 $f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^{\circ}\text{C}$ 

Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

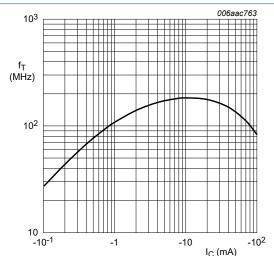


Fig. 9. Transition frequency as a function of collector current; typical values of built-in transistor

50 V, 100 mA PNP resistor-equipped transistor; R1 = 2.2 kΩ, R2: 10 kΩ

## 11. Test information

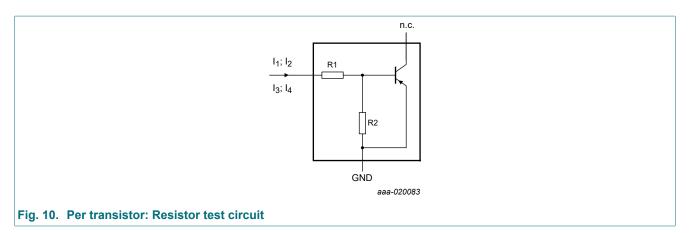
#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

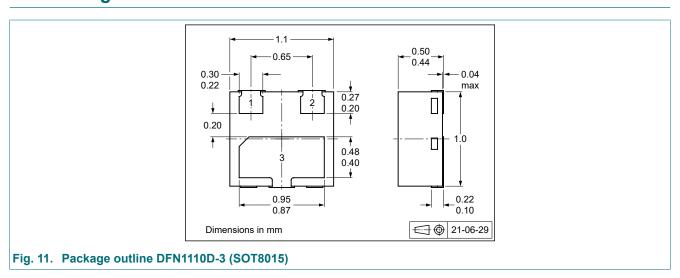


#### **Resistor test conditions**

Table 8. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>1</sub>	l <sub>2</sub>	l <sub>3</sub>	14
PDTA123YQB	2.2	10	-1300 µA	-1500 µA	350 µA	450 µA

# 12. Package outline



50 V, 100 mA PNP resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2: 10 k $\Omega$ 

# 13. Soldering

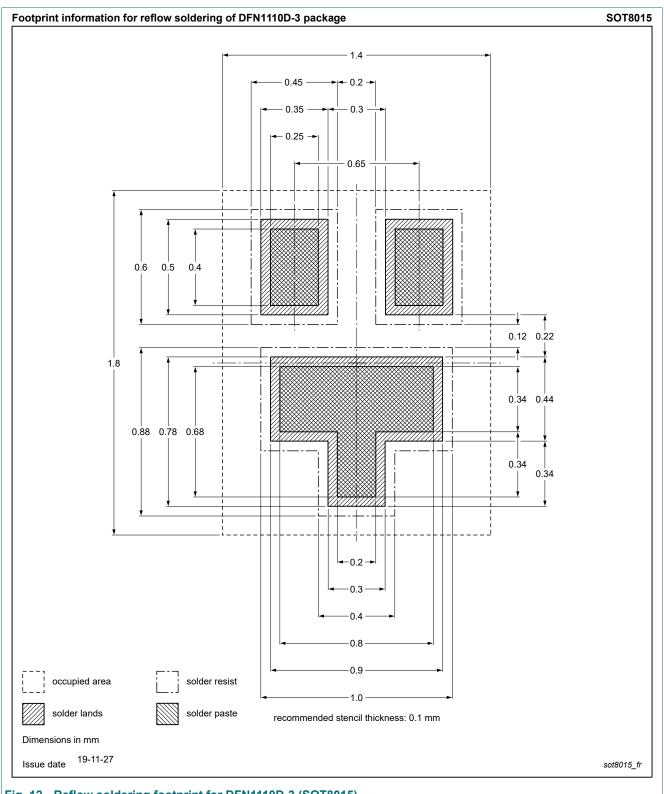


Fig. 12. Reflow soldering footprint for DFN1110D-3 (SOT8015)

# 14. Revision history

### Table 9. Revision history

Data sheet ID	Release date		Change notice	Supersedes
PDTA123YQB v.1	20231124	Product data sheet	-	-

#### 50 V, 100 mA PNP resistor-equipped transistor; R1 = 2.2 kΩ, R2: 10 kΩ

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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### 50 V, 100 mA PNP resistor-equipped transistor; R1 = 2.2 k $\Omega$ , R2: 10 k $\Omega$

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